

High voltage fast-switching NPN power transistor

Features

- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

- Compact fluorescent lamps (CFLS)
- SMPS for battery charger

Description

The device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

The STBV32G and STBV32G-AP are supplied using halogen-free molding compound.

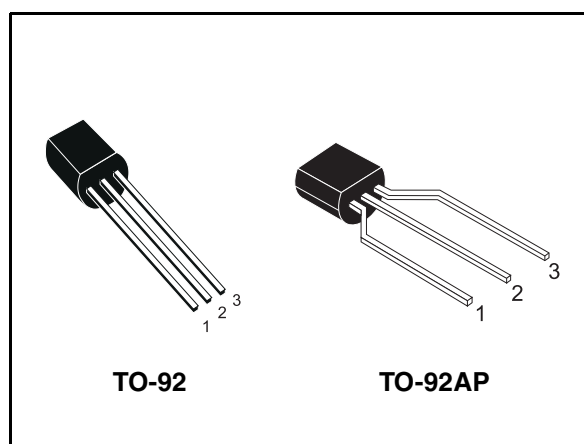


Figure 1. Internal schematic diagram

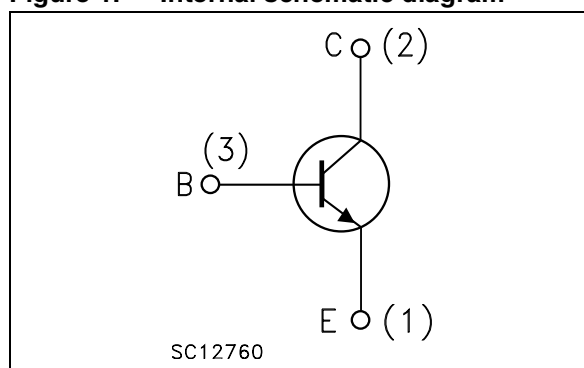


Table 1. Device summary

| Order codes | Marking | Package | Packaging |
|-------------|---------|---------|-----------|
| STBV32 | BV32 | TO-92 | Bulk |
| STBV32G | BV32G | TO-92 | Bulk |
| STBV32-AP | BV32 | TO-92AP | Ammopack |
| STBV32G-AP | BV32G | TO-92AP | Ammopack |

1 Electrical ratings

Table 2. Absolute maximum rating

| Symbol | Parameter | Value | Unit |
|-----------|---|---------------|------|
| V_{CES} | Collector-emitter voltage ($V_{BE} = 0$) | 700 | V |
| V_{CEO} | Collector-emitter voltage ($I_B = 0$) | 400 | V |
| V_{EBO} | Collector-base voltage ($I_C = 0$, $I_B = 0.5A$, $t_P < 10$ ms) | $V_{(BR)EBO}$ | V |
| I_C | Collector current ($f \geq 100$ Hz, duty-cycle $\leq 50\%$, $T_C = 25$ °C) | 1.5 | A |
| I_{CM} | Collector peak current ($t_P < 5$ ms) | 3 | A |
| I_B | Base current | 0.5 | A |
| I_{BM} | Base peak current ($t_P < 5$ ms) | 1.5 | A |
| P_{TOT} | Total dissipation at $T_C = 25$ °C | 1.5 | W |
| T_{stg} | Storage temperature | -65 to 150 | °C |
| T_J | Max. operating junction temperature | 150 | |

Table 3. Thermal data

| Symbol | Parameter | Value | Unit |
|----------------|--------------------------------------|-------|------|
| $R_{thj-case}$ | Thermal resistance junction-case max | 83.3 | °C/W |

2 Electrical characteristics

($T_{\text{case}} = 25\text{ °C}$; unless otherwise specified)

Table 4. Electrical characteristics

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|--|--|--|------|------|------|---------------|
| I_{CES} | Collector cut-off current ($V_{\text{BE}} = 0$) | $V_{\text{CE}} = 700\text{ V}$ | | | 1 | mA |
| | | $V_{\text{CE}} = 700\text{ V}$ $T_{\text{C}} = 125\text{ °C}$ | | | 5 | mA |
| $V_{(\text{BR})\text{EBO}}$ | Emitter-base breakdown voltage ($I_{\text{C}} = 0$) | $I_{\text{E}} = 10\text{ mA}$ | 9 | | 18 | V |
| $V_{\text{CEO(sus)}}^{(1)}$ | Collector-emitter sustaining voltage ($I_{\text{B}} = 0$) | $I_{\text{C}} = 10\text{ mA}$ | 400 | | | V |
| $V_{\text{CE(sat)}}^{(1)}$ | Collector-emitter saturation voltage | $I_{\text{C}} = 0.5\text{ A}$ $I_{\text{B}} = 100\text{ mA}$ | | | 0.5 | V |
| | | $I_{\text{C}} = 1\text{ A}$ $I_{\text{B}} = 250\text{ mA}$ | | | 1 | V |
| | | $I_{\text{C}} = 1.5\text{ A}$ $I_{\text{B}} = 500\text{ mA}$ | | | 1.5 | V |
| $V_{\text{BE(sat)}}^{(1)}$ | Base-emitter saturation voltage | $I_{\text{C}} = 0.5\text{ A}$ $I_{\text{B}} = 100\text{ mA}$ | | | 1 | V |
| | | $I_{\text{C}} = 1\text{ A}$ $I_{\text{B}} = 250\text{ mA}$ | | | 1.2 | V |
| h_{FE} | DC current gain | $I_{\text{C}} = 0.5\text{ mA}$ $V_{\text{CE}} = 2\text{ V}$ | 20 | | | |
| | | $I_{\text{C}} = 0.5\text{ A}$ $V_{\text{CE}} = 2\text{ V}$ | 8 | | 25 | |
| | | $I_{\text{C}} = 1\text{ A}$ $V_{\text{CE}} = 2\text{ V}$ | 5 | | 25 | |
| t_{r} t_{s} t_{f} | Resistive load Rise time Storage time Fall time | $I_{\text{C}} = 1\text{ A}$ $t_{\text{p}} = 25\text{ }\mu\text{s}$ | | | 1 | μs |
| | | $I_{\text{B1}} = -I_{\text{B2}} = 200\text{ mA}$ | | | 4 | μs |
| | | $V_{\text{CC}} = 125\text{ V}$ <i>Figure 12.</i> | | | 0.7 | μs |
| t_{s} | Inductive Load Storage time | $I_{\text{C}} = 1\text{ A}$ $V_{\text{clamp}} = 300\text{ V}$ $I_{\text{B1}} = 200\text{ mA}$ $V_{\text{BE(off)}} = -5\text{ V}$ $L = 50\text{ mH}$ $R_{\text{BB}} = 0$ <i>Figure 13.</i> | | 0.8 | | μs |

1. Pulsed duration = 300 μs , duty cycle $\leq 1.5\%$

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

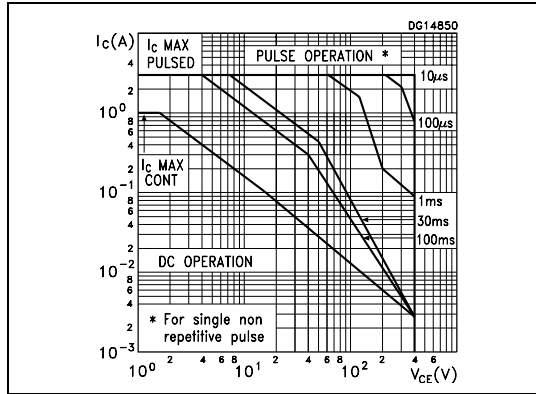


Figure 3. Derating curve

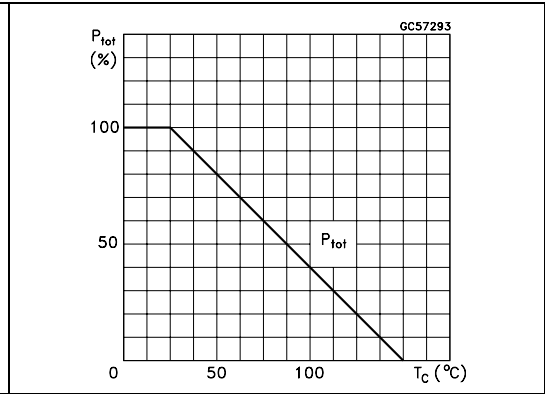


Figure 4. Output characteristics

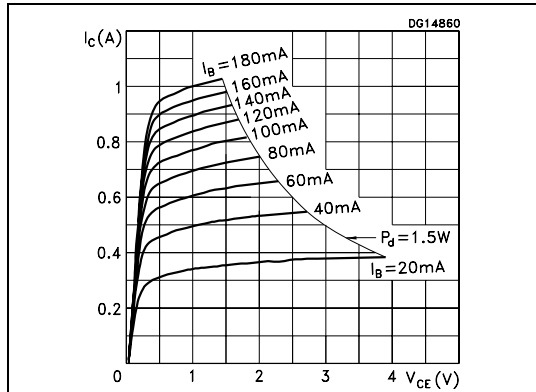


Figure 5. Reverse biased safe operating area

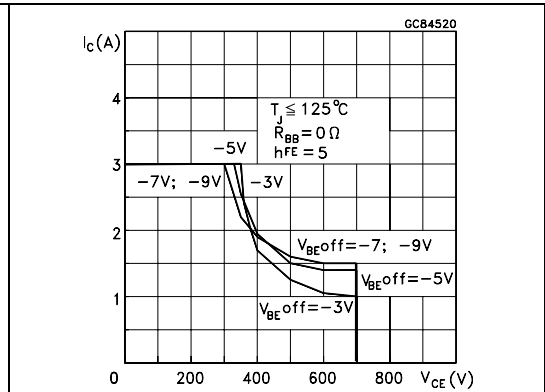


Figure 6. DC current gain

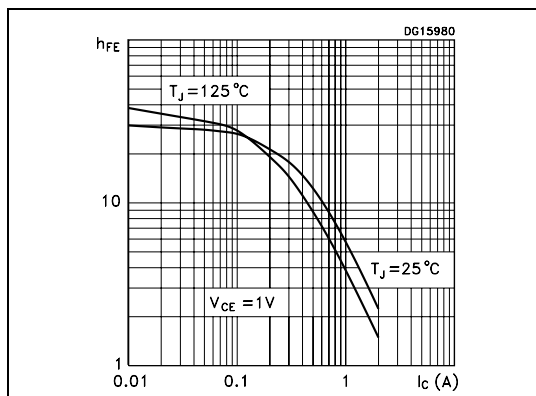


Figure 7. DC current gain

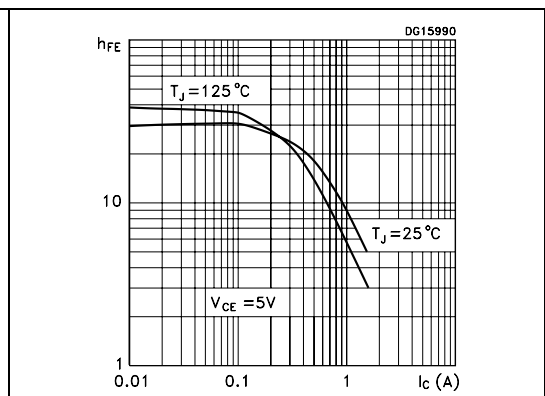


Figure 8. Collector-emitter saturation voltage

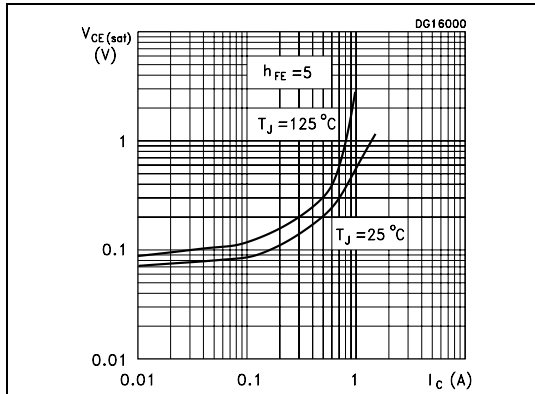


Figure 9. Base-emitter saturation voltage

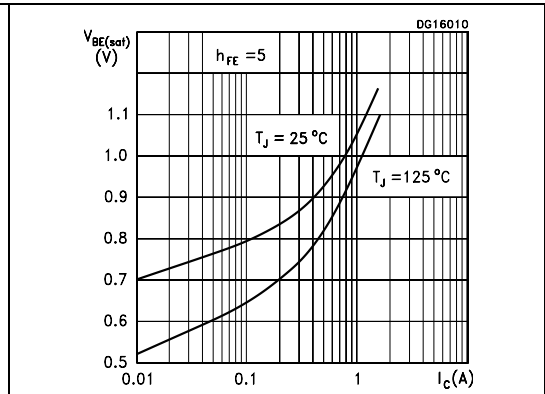


Figure 10. Inductive load switching time

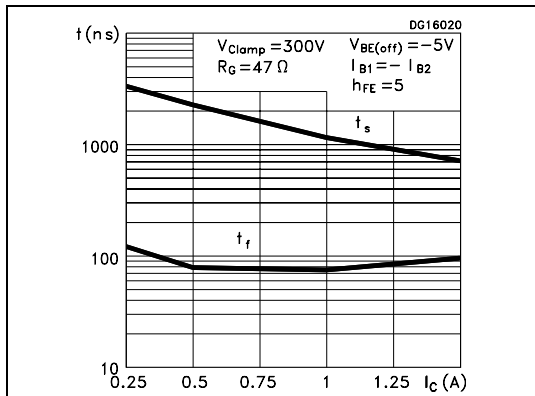
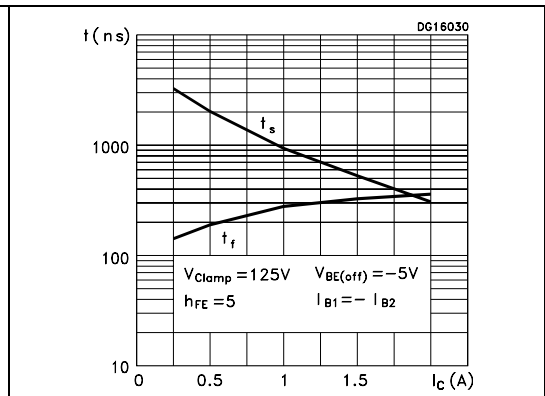


Figure 11. Resistive load switching time



2.2 Test circuits

Figure 12. Resistive load switching test circuit

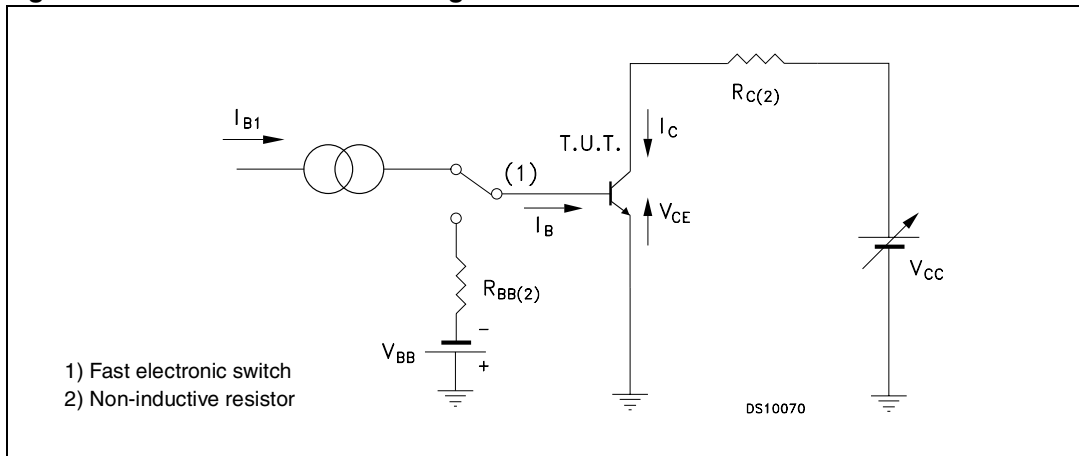
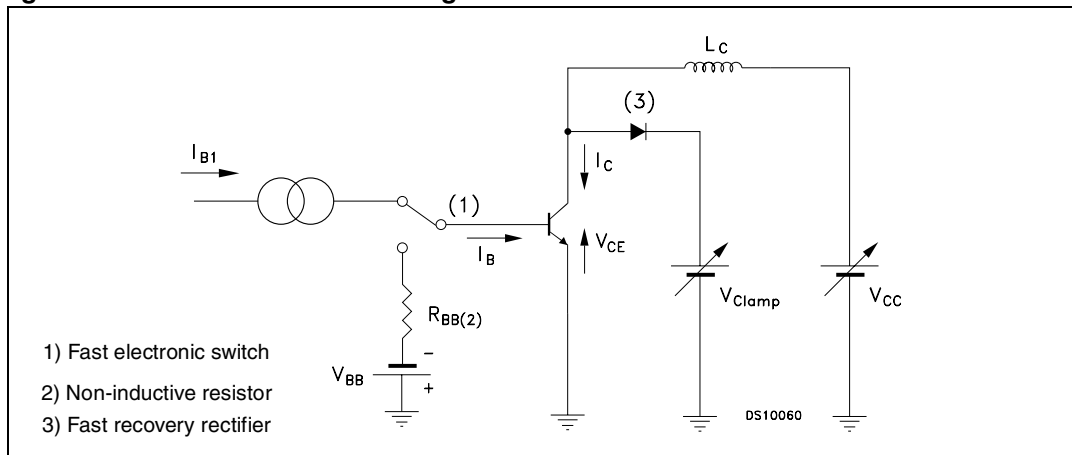


Figure 13. Inductive load switching test circuit

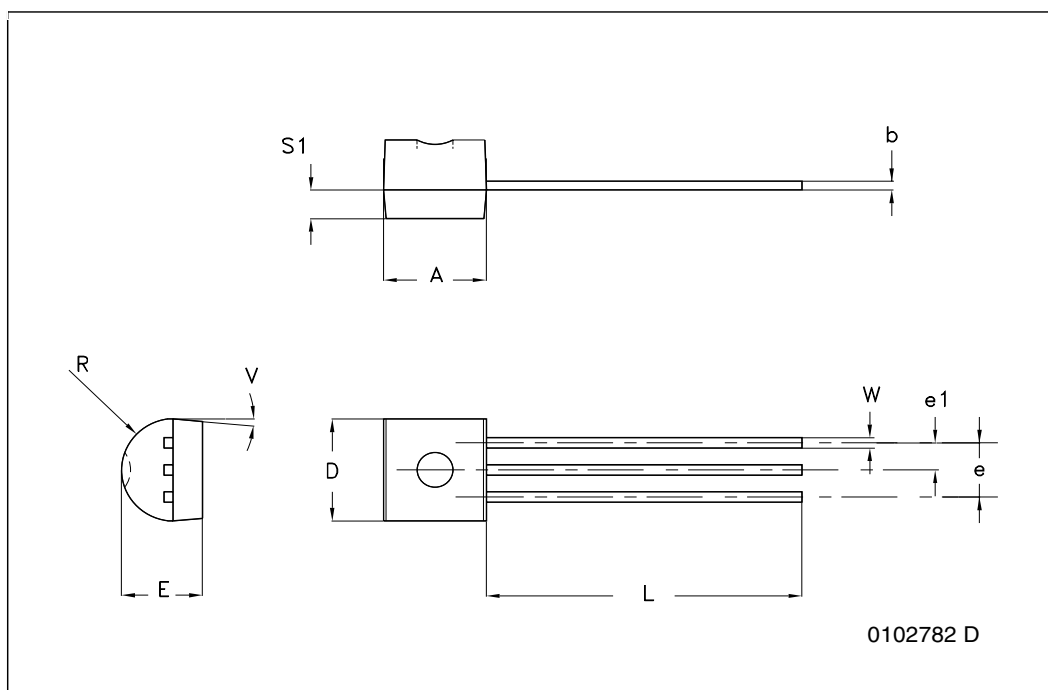


3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

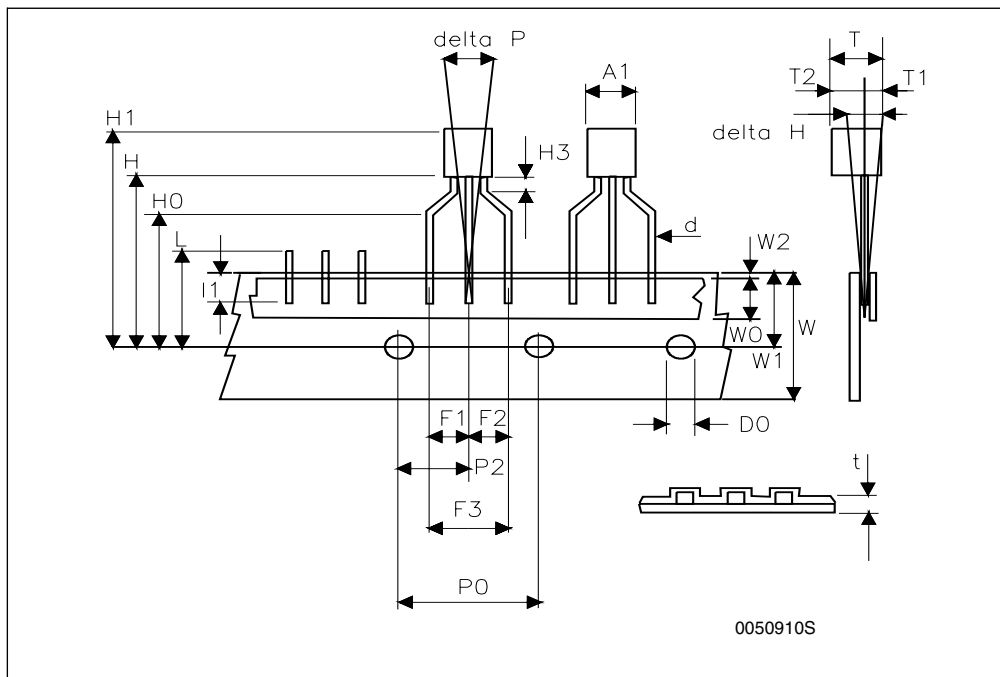
TO-92 bulk shipment mechanical data

| DIM. | mm. | | |
|------|-------|-----|-------|
| | MIN. | TYP | MAX. |
| A | 4.32 | | 4.95 |
| b | 0.36 | | 0.51 |
| D | 4.45 | | 4.95 |
| E | 3.30 | | 3.94 |
| e | 2.41 | | 2.67 |
| e1 | 1.14 | | 1.40 |
| L | 12.70 | | 15.49 |
| R | 2.16 | | 2.41 |
| S1 | 0.92 | | 1.52 |
| W | 0.41 | | 0.56 |
| V | | 5° | |



TO-92 ammopack shipment (suffix"-AP") mechanical data

| Dim. | mm | | |
|---------|-------|-------|-------|
| | Min | Typ | Max |
| A1 | | | 4.80 |
| T | | | 3.80 |
| T1 | | | 1.60 |
| T2 | | | 2.30 |
| d | | | 0.48 |
| P0 | 12.50 | 12.70 | 12.90 |
| P2 | 5.65 | 6.35 | 7.05 |
| F1,F2 | 2.44 | 2.54 | 2.94 |
| F3 | 4.98 | 5.08 | 5.48 |
| delta H | -2.00 | | 2.00 |
| W | 17.50 | 18.00 | 19.00 |
| W0 | 5.70 | 6.00 | 6.30 |
| W1 | 8.50 | 9.00 | 9.25 |
| W2 | | | 0.50 |
| H | 18.50 | | 20.50 |
| H3 | 0.5 | 1 | 1.5 |
| H0 | 15.50 | 16.00 | 16.50 |
| H1 | | | 25.00 |
| D0 | 3.80 | 4.00 | 4.20 |
| t | | | 0.90 |
| L | | | 11.00 |
| I1 | 3.00 | | |
| delta P | -1.00 | | 1.00 |



4 Revision history

Table 5. Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 02-Jul-2008 | 8 | Added halogen-free molding compound package. |

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